

<b>SURFACE MOUNT GENERAL PURPOSE SILICON RECTIFIER</b>	Reverse Voltage - 50 to 1000 Volts Forward Current -1.0 Ampere																																																																																																																													
<p style="text-align: center;"><b>SOD-123FL</b></p> <p style="text-align: center; font-size: small;">Dimensions in inches and (millimeters)</p>	<p><b>Features</b></p> <ul style="list-style-type: none"> <li>◆ Glass passivated device</li> <li>◆ Ideal for surface mounted applications</li> <li>◆ Low reverse leakage</li> <li>◆ Metallurgically bonded construction</li> <li>◆ High temperature soldering guaranteed: 260°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension</li> </ul> <p><b>Mechanical Data</b></p> <p><b>Case:</b> SOD-123FL molded plastic body over passivated chip  <b>Terminals:</b> Solderable per MIL-STD-750, Method 2026  <b>Polarity:</b> Color band denotes cathode end  <b>Mounting Position:</b> Any  <b>Weight:</b> 0.0007 ounce, 0.02 grams</p>																																																																																																																													
<b>MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS</b>																																																																																																																														
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	<table border="1" style="width:100%; border-collapse: collapse; font-size: x-small;"> <thead> <tr> <th style="width:15%;">SYMBOLS</th> <th>DSR1A</th> <th>DSR1B</th> <th>DSR1D</th> <th>DSR1G</th> <th>DSR1J</th> <th>DSR1K</th> <th>DSR1M</th> <th>UNITS</th> </tr> <tr> <td></td> <th>S1A</th> <th>S1B</th> <th>S1D</th> <th>S1G</th> <th>S1J</th> <th>S1K</th> <th>S1M</th> <td></td> </tr> </thead> <tbody> <tr> <td>Maximum repetitive peak reverse voltage</td> <td>V<sub>RRM</sub></td> <td>50</td> <td>100</td> <td>200</td> <td>400</td> <td>600</td> <td>800</td> <td>1000</td> <td>V</td> </tr> <tr> <td>Maximum RMS voltage</td> <td>V<sub>RMS</sub></td> <td>35</td> <td>70</td> <td>140</td> <td>280</td> <td>420</td> <td>560</td> <td>700</td> <td>V</td> </tr> <tr> <td>Maximum DC blocking voltage</td> <td>V<sub>DC</sub></td> <td>50</td> <td>100</td> <td>200</td> <td>400</td> <td>600</td> <td>800</td> <td>1000</td> <td>V</td> </tr> <tr> <td>Maximum average forward rectified current at T<sub>L</sub>=100°C (NOTE 1)</td> <td>I<sub(av)< sub=""></sub(av)<></td> <td colspan="6" style="text-align: center;">1.0</td> <td></td> <td>A</td> </tr> <tr> <td>Peak forward surge current 8.3ms single half sine-wave superimposed on rated load</td> <td>I<sub>FSM</sub></td> <td colspan="6" style="text-align: center;">25.0</td> <td></td> <td>A</td> </tr> <tr> <td>Maximum instantaneous forward voltage at 1.0A</td> <td>V<sub>F</sub></td> <td colspan="6" style="text-align: center;">1.1</td> <td></td> <td>V</td> </tr> <tr> <td>Maximum DC reverse current T<sub>A</sub>=25°C</td> <td rowspan="2">I<sub>R</sub></td> <td colspan="6" style="text-align: center;">10.0</td> <td rowspan="2"></td> <td rowspan="2">μA</td> </tr> <tr> <td>at rated DC blocking voltage T<sub>A</sub>=125°C</td> <td colspan="6" style="text-align: center;">50.0</td> </tr> <tr> <td>Typical junction capacitance (NOTE 2)</td> <td>C<sub>J</sub></td> <td colspan="6" style="text-align: center;">4</td> <td></td> <td>pF</td> </tr> <tr> <td>Typical thermal resistance (NOTE 3)</td> <td>R<sub>θJA</sub></td> <td colspan="6" style="text-align: center;">95</td> <td></td> <td>°C/W</td> </tr> <tr> <td>Operating junction and storage temperature range</td> <td>T<sub>J</sub>, T<sub>STG</sub></td> <td colspan="6" style="text-align: center;">-55 to +150</td> <td></td> <td>°C</td> </tr> </tbody> </table>	SYMBOLS	DSR1A	DSR1B	DSR1D	DSR1G	DSR1J	DSR1K	DSR1M	UNITS		S1A	S1B	S1D	S1G	S1J	S1K	S1M		Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V	Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V	Maximum DC blocking voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V	Maximum average forward rectified current at T <sub>L</sub> =100°C (NOTE 1)	I <sub(av)< sub=""></sub(av)<>	1.0							A	Peak forward surge current 8.3ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	25.0							A	Maximum instantaneous forward voltage at 1.0A	V <sub>F</sub>	1.1							V	Maximum DC reverse current T <sub>A</sub> =25°C	I <sub>R</sub>	10.0							μA	at rated DC blocking voltage T <sub>A</sub> =125°C	50.0						Typical junction capacitance (NOTE 2)	C <sub>J</sub>	4							pF	Typical thermal resistance (NOTE 3)	R <sub>θJA</sub>	95							°C/W	Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150							°C
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<p><b>Note:</b> 1. Averaged over any 20ms period.                  2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.                  3. PCB mounted on 0.2*0.2" (5.0*5.0mm) copper pad area.</p>																																																																																																																														

**RATINGS AND CHARACTERISTIC CURVES DSR1A THRU DSR1M**

